



#### **60V N-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> T <sub>A</sub> = +25°C
001/	44mΩ @ V <sub>GS</sub> = 10V	5.0A
60V	$60m\Omega @ V_{GS} = 4.5V$	4.3A

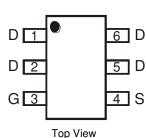
# **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Backlighting



Top View



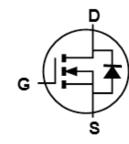
Pin Configuration

## **Features and Benefits**

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low Input Capacitance
- Low On-Resistance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: TSOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Tin Finish Annealed over Copper Leadframe.
  Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.013 grams (Approximate)



Equivalent Circuit

#### Ordering Information (Note 5)

Part Number	Case	Packaging
DMN6040SVTQ-7	TSOT26	3,000/Tape & Reel
DMN6040SVTQ-13	TSOT26	10,000/Tape & Reel

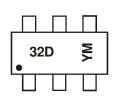
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Automotive products are AEC-Q101 qualified and are PPAP capable. Please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.
 For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



32D = Product Type Marking Code YM = Date Code Marking Y = Year (ex: X = 2010)

M = Month (ex: 9 = September)

#### Date Code Key

Duie Coue ney												
Year	2010		2017	2018	3 20 <sup>.</sup>	19 20	)20 2	2021	2022	2023	2024	2025
Code	Х		E	F	G	ì	H	I	J	K	L	М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	5.0 4.0	А
Continuous Drain Current (Note 7) $V_{GS} = 10V$	t<10s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	6.3 5.0	А
	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	4.3 3.4	А
Continuous Drain Current (Note 7) $V_{GS} = 5V$	t<10s	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	5.4 4.3	А
Maximum Body Diode Forward Current (Note 7)	•	ls	2.1	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		I <sub>DM</sub>	30	А	
Avalanche Current (Note 8) L = 0.1mH		I <sub>AR</sub>	14.2	А	
Avalanche Energy (Note 8) L = 0.1mH	E <sub>AR</sub>	10	mJ		

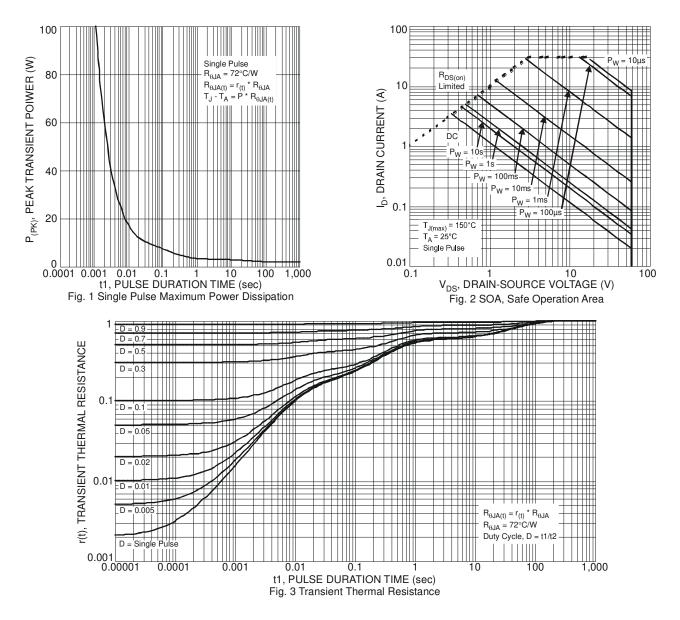
# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Bower Discipation (Note 6)	$T_A = +25^{\circ}C$	Р	1.2	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	0.75	vv
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Р	106	°C/W
memai Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	69	°C/W
Total Power Dissipation (Note 7)	T <sub>A</sub> = +25°C	Pn	1.8	W
Total Fower Dissipation (Note 7)	$T_A = +70^{\circ}C$	PD	1.1	vv
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	Р	68	°C/W
Thermal Resistance, Junction to Amblent (Note 7)	t<10s	R <sub>0JA</sub>	44	°C/W
Thermal Resistance, Junction to Case (Note 7)		R <sub>θJC</sub>	20	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

8. IAR and EAR rating are based on low frequency and duty cycles to keep  $T_J = +25^{\circ}C$ .





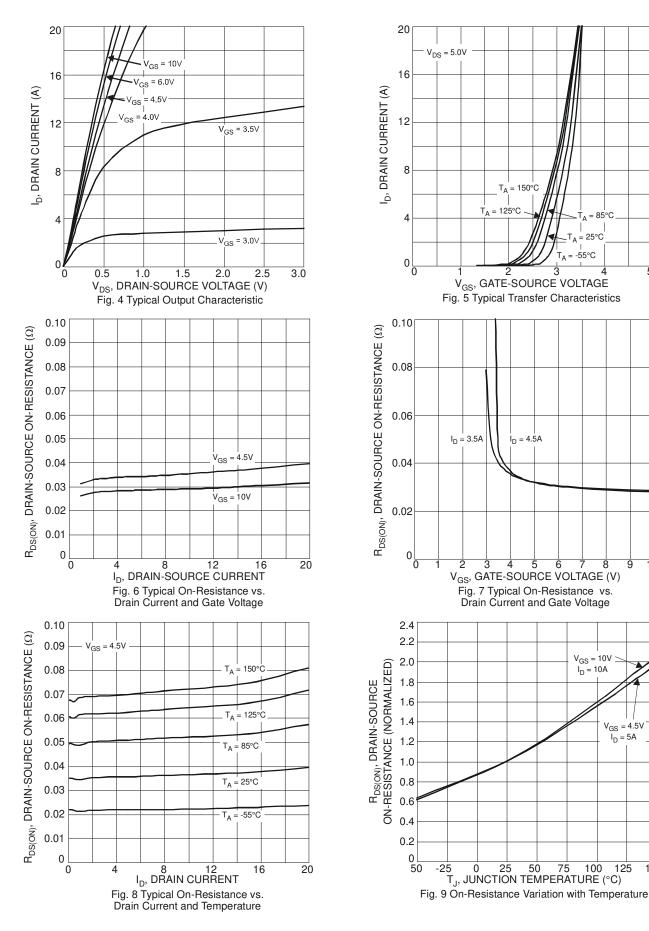


# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						-
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_		V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	100	nA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	_	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$
Static Drain-Source On-Resistance		_	30	44	mΩ	$V_{GS} = 10V, I_D = 4.3A$
	R <sub>DS(ON)</sub>	_	35	60	11152	$V_{GS} = 4.5V, I_D = 4A$
Forward Transfer Admittance	Y <sub>FS</sub>	_	4.5		S	$V_{DS} = 10V, I_D = 4.3A$
Diode Forward Voltage	V <sub>SD</sub>	_	0.7	1.2	V	$V_{GS} = 0V, I_S = 1A$
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	CISS	_	1,287			
Output Capacitance	C <sub>OSS</sub>	_	57	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>RSS</sub>	_	44	_		1 = 1.000112
Gate Resistance	R <sub>G</sub>	_	1.2		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Q <sub>G</sub>	_	22.4	_		
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Q <sub>G</sub>	_	10.4		nC	V 20V L 4.24
Gate-Source Charge	Q <sub>GS</sub>	_	4.9		110	$V_{DS} = 30V, I_D = 4.3A$
Gate-Drain Charge	Q <sub>GD</sub>		3.0			
Turn-On Delay Time	t <sub>D(ON)</sub>		6.6			
Turn-On Rise Time	t <sub>R</sub>		8.1			$V_{GS} = 10V, V_{DD} = 30V, R_G = 6\Omega,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		20.1		ns	$I_D = 4.3A$
Turn-Off Fall Time	t <sub>F</sub>		4.0		1	
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	18	_	ns	I <sub>S</sub> = 4.3A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	11.9	_	nC	I <sub>S</sub> = 4.3A, dl/dt = 100A/µs

Notes:9. Short duration pulse test used to minimize self-heating effect.10. Guaranteed by design. Not subject to product testing.





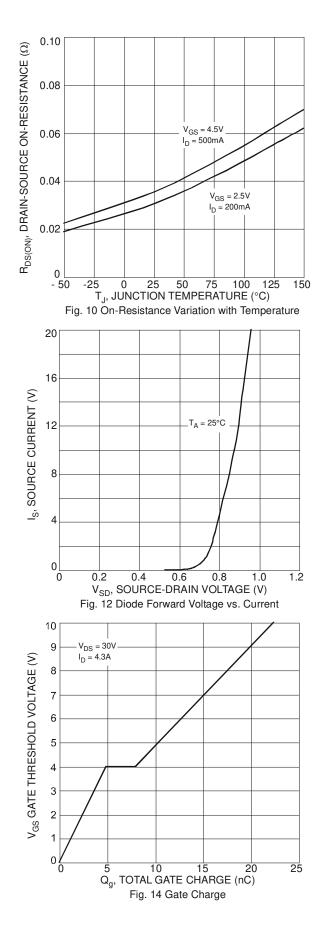
150

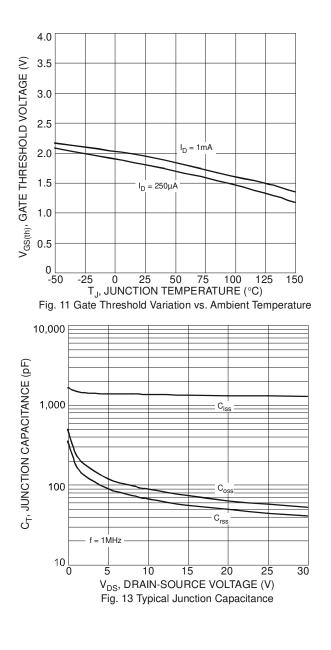
8 9 10

 $V_{GS} = 4.5V$  $I_D = 5A$ 

125



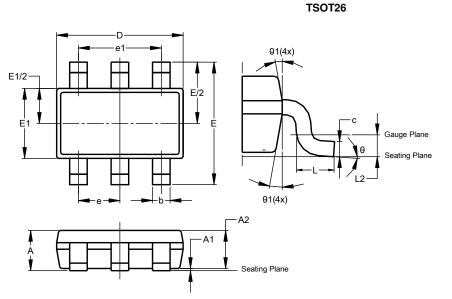






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

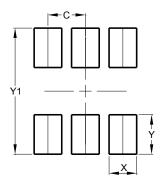


TSOT26									
Dim	Min	Max	Тур						
Α	-	1.00	-						
A1	0.010	0.100	-						
A2	0.840	0.900	-						
D	2.800	3.000	2.900						
Е	2.800 BSC								
E1	1.500	1.700	1.600						
b	0.300	0.450	-						
С	0.120	0.200	-						
e	0	0.950 BSC							
e1	1	.900 BS	C						
L	0.30	0.30 0.50							
L2	0	.250 BS	С						
θ	0°	8°	4°						
θ1	4°	12°	_						
Α	All Dimensions in mm								

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

TSOT26



Dimensions	Value (in mm)
С	0.950
Х	0.700
Y	1.000
Y1	3.199



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